



TV/VCR TUNER IC WITH DC/DC CONVERTER

FEATURES

- Single Chip Mixer/Oscillator, Synthesizer, and 30-V DC/DC Converter for Tuning Amplifier
- VHF-L, VHF-H, UHF 3-Band Local Oscillator
- I²C Bus Protocol
- Four Data Bytes Transmission
- Low Noise DC/DC Converter
- 4ch NPN Emitter Follower Type Band Switch Drivers
- 4ch NPN Open Collector Type Ports
- Programmable Reference Divider Ratio (31.25 kHz, 50 kHz, or 62 kHz)
- 5-V Power Supply
- 38-Pin TSSOP Package

DESCRIPTION

The SN761677 is a single-chip synthesized tuner IC designed for TV/VCR tuning systems. The circuit consists of a PLL synthesizer, 3-band local oscillators and mixer, 30-V dc/dc converter for tuning the amplifier, four NPN emitter follower band drivers, four NPN open collector ports, and is available in a small package outline. The 15-bit programmable counter and reference divider are controlled by I²C bus control. Tuning step frequency is selectable by the reference divider ratio for a 4-MHz Xtal oscillator.

DA PACKAGE (TOP VIEW) 38-PIN TSSOP (DA)

VLO OSC B 🖂	1	38 🖂 UHF RF IN2
VLO OSC C 🖂	2	37 📥 UHF RF IN1
OSC GND 🖂	3	36 📥 VHF RF IN2
VHI OSC B 🖂	4	35 📥 VHF RF IN1
VHI OSC C 🖂	5	34 📩 RF GND
UHF OSC B1 🖂	6	33 📩 MIX OUT2
UHF OSC C1 🖂	7	32 📩 MIX OUT1
UHF OSC C2 🖂	8	31 📥 BS1
UHF OSC B2 🖂	9	30 🖂 BS2
IF GND 💳	10	29 📥 BS3
IF OUT1 🖂	11	28 📥 BS4
IF OUT2 🖂	12	27 📥 P5
VCC 🖂	13	26 📥 ADC/TEST
СР 🗔	14	25 📥 P6
VTU 🖂	15	24 📥 AS
TUVCC(5V) 🖂	16	23 📥 SDA
TUGND 💳	17	22 📥 SCL
VDC(DC/DCout)	18	21 📥 P7
XTAL 🖂	19	20 📩 P8



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range unless otherwise noted⁽¹⁾

		UNIT			
Supply voltage ⁽²⁾ , V _{CC}	VCC, TUVCC	–0.4 V to 7 V			
Input voltage 1 ⁽²⁾ , V _{GND} RF GND, OSC GND, TUGND		–0.4 V to 0.4 V			
Input voltage 2 ⁽²⁾ , V _(VTU)	VTU (4)	–0.4 V to 35 V			
Input voltage 3 $^{(2)}$, V _{IN}	Other input pins	–0.4 V to 7 V			
Continuous total dissipation $^{(3)}$, PD	T _A ≤25°C	1168 mW			
Operating free-air temperature, TA		–20°C to 85°C			
Storage temperature range, T _{Stg}		–65°C to 150°C			
Maximum junction temperature, TJ		150°C			
Maximum lead temperature 1,6 mm (1/16 ir	260°C				
Maximum short circuit time, tSC(max)	Maximum short circuit time, t _{SC(max)} All pins to VCC/TUVCC, IFGND, OSCGND, RFGND, TUGND				

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Voltage values are with respect to the IF GND of the circuit.

(3) Derating factor is 9.34 mW/°C for $T_A \le 25^{\circ}C$.

(4) 30 V max, when input from external power supply.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
Supply voltage, VCC		4.5	5	5.5	V
Band switch driver source current, I_{BS}	One port on			10	mA
NPN port sink current, INPN	One port on		-10	-15	mA
Operating free-air temperature, TA		-20		85	°C

CAUTION:

It is advised that precautions be taken to avoid damage due to high static voltages or electrostatic fields while handling this device. UHF OSC (pins 6–9) can withstand 1.5 kV and all other pins can withstand 2 kV, according to the Human Body Model (1.5 k Ω , 100 pF).

ELECTRICAL CHARACTERISTICS

 V_{CC} = 4.5 V to 5.5 V, T_A = -20°C to 85°C (unless otherwise noted)(1)

	PARAMETER	TEST CONDITIONS	MIN	ΤΥΡ	MAX	UNIT
Total Devic	e and Serial Interface					
ICC1	Supply current 1 (VCC)			75	95	mA
ICC2	Supply current 2 (VCC)	One band switch on $(I_{BS} = 10 \text{ mA})$		85	105	mA
ICC3	Supply current 3 (TUVCC)	I _{VDC} = 50 μA		4	10	mA
VIH	High-level input voltage (SCL, SDA)		3			V
VIL	Low-level input voltage (SCL, SDA)				1.5	V
IIН	High-level input current (SCL, SDA)				10	μΑ
۱ _{IL}	Low-level input current (SCL, SDA)		-10			μΑ
VPOR	Power-on reset supply voltage	Threshold of supply voltage between reset and operation mode	2.1	3.7	4	V
DC/DC Con	verter					
VO(VDC)	Output voltage (VDC)	I _{VDC} = 50 μA		35		V
IC(VDCM)	Output current (VDC)			230		μΑ
t _S	Output settling time (VDC)	From $V_{TUVCC} > 4.5 V$ to $V_{O(VDC)} < 28 V$		100		ms
I ² C Interfac	e	· · · · · · · · · · · · · · · · · · ·				
VASH	Address select high-input voltage (AS)	V _{CC} = 5 V	4.5		5	V
VASM	Address select mid-input voltage (AS)	$V_{CC} = 5 V$	2		3	V
VASL	Address select low-input voltage (AS)	$V_{CC} = 5 V$			0.5	V
IASH	Address select high-input current (AS)				10	μΑ
IASL	Address select low-input current (AS)		-10			μΑ
VI(ADC)	ADC input voltage	See Table 9	0		Vcc	V
IIH(ADH)	ADC high-level input current	$V_{I(ADC)} = V_{CC}$			10	μΑ
lil(ADL)	ADC low-level input current	$V_{I(ADC)} = 0 V$	-10			μΑ
VOL	Low-level output voltage (SDA)	$V_{CC} = 5 V$, $I_{OL} = 3 mA$			0.4	V
l _{lkg} (SDA)	High-level output leakage current (SDA)	V _{SDA} = 5.5 V			10	μA
FSCL	Clock frequency (SCL)			100	400	kHz
^t h(DAT)	Data hold time	See timing chart in Figure 1	0			μs
^t BUF	Bus free time		1.3			μs
^t h(STA)	Start hold time		0.6			μs
th(low)	SCL low hold time		0.6			μs
^t h(lhigh)	SCL high hold time		0.6			μs
^t su(STA)	Start setup time		0.6			μs
^t su(DAT)	Data setup time		0.1			μs
t _r	SCL, SDA rise time		1		0.3	μs
tf	SCL, SDA fall time				0.3	μs
^t su(STO)	STOP setup time		0.6			μs



ELECTRICAL CHARACTERISTICS (Continued) $V_{CC} = 4.5 V \text{ to } 5.5 V$, $T_A = -20^{\circ}\text{C} \text{ to } 85^{\circ}\text{C} \text{ (unless otherwise noted)}^{(1)}$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
PLL and NPN	Port					
		14-bit frequent word	256		16383	
Ν	Divider ratio	15-bit frequent word	256		32767	
FXTAL	Crystal oscillator	Rxtal = 25Ω to 300Ω		4		MHz
Z _{XTAL}	Crystal oscillator input impedance	$V_{CC} = 5 V$, $T_A = 25^{\circ}C$		2.3		kΩ
VXTALIN	External crystal oscillator input amplitude		400			mV _{p-p}
VO(TU)	Tuning amplifier low-level output voltage	$R_L = 27 k\Omega$		0.4	0.7	V
IIH(CPH)	Charge pump high-level input current	CP = 1		40		μΑ
IIL(CPH)	Charge pump low-level input current	CP = 0		10		μΑ
V _{O(CP)}	Charge pump output voltage	In lock		1.95		V
likg(CPOFF)	Charge pump leakage current	$T2 = 0, T1 = 1, V_{O(CP)} = 2 V, T_{A} = 25^{\circ}C$	-15		15	nA
IBS	Band switch driver source current				10	mA
VO(SBS1)	Desidentitation and a desidentia	$I_{BS} = 10 \text{ mA}$	3			V
V _{O(SBS2)}	Band switch driver output voltage	$I_{BS} = 10 \text{ mA}, V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$	3.5	3.9		V
Ilkg(BSOFF)	Band switch driver leakage current	$V_{BS} = 0 V$			3	μΑ
INPN	NPN port sink current				-15	mA
VO(SN1)		I _{NPN} = 100 μA			0.2	V
VO(SN2)	NPN port output voltage	I _{NPN} = 10 mA			0.5	V
likg(NPNOFF)	NPN port leakage current	V _{CC} = 5.5 V, V _{NPN} = 1.5 V			1	μA

ELECTRICAL CHARACTERISTICS

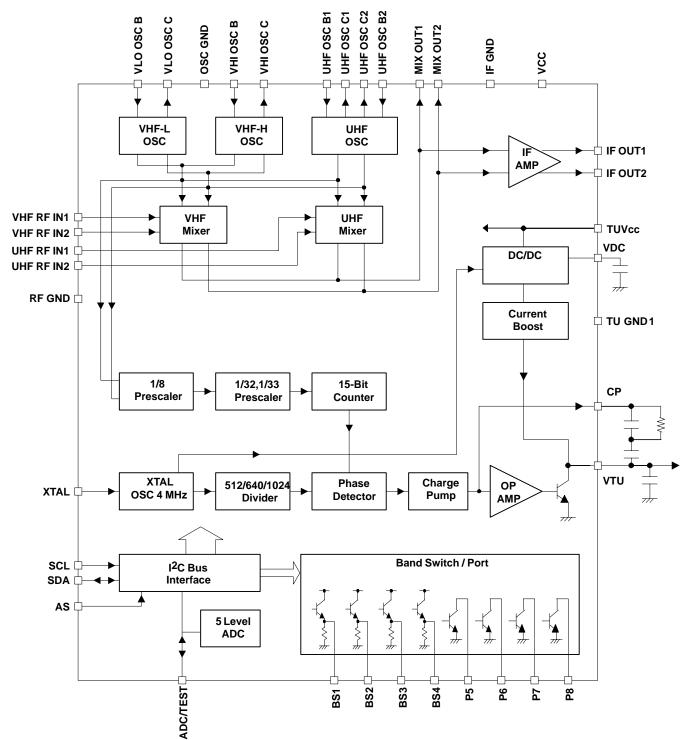
 $V_{CC} = 5 V$, $T_A = -25^{\circ}C$, measured in reference measurement circuit at 50- Ω system, IF filter characteristics: $f_{peak} = 43 \text{ MHz}$; (unless otherwise noted)(1)

	PARAMETER	CONDITION	MIN	TYP	MAX	UNIT
MIXER, O	SCILLATOR, IF AMPLIFIER		•			
G _{c1}		F _{in} = 58 MHz ₍₁₎				in
G _{c3}	Conversion gain (mixer~IF amplifier) VHF low	F _{in} = 130 MHz	23	26	29	dB
G _{c4}		F _{in} = 136 MHz ₍₁₎				in
G _{c6}	Conversion gain (mixer~IF amplifier) VHF high	F _{in} = 364 MHz	23	26	29	dB
G _{c7}		F _{in} = 370 MHz ₍₁₎		07		.10
G _{c9}	Conversion gain (mixer~IF amplifier) VHF–UHF	F _{in} = 804 MHz	24	27	30	dB
NF ₁		F _{in} = 55.25 MHz		11		.10
NF3	Noise figure VHF low	F _{in} = 127.25 MHz				dB
NF ₄		F _{in} = 133.25 MHz				.10
NF ₆	Noise figure VHF high	F _{in} = 361.25 MHz		11		dB
NF7		F _{in} = 367.25 MHz		10		JD
NF9	Noise figure UHF	F _{in} = 801.25 MHz		11		dB
CM ₁		F _{in} = 55.25 MHz ⁽²⁾				
CM ₃	1% cross modulation distortion VHF low	F _{in} = 127.25 MHz		89		dBμV
CM ₄	40/ second data distantian MUT bish	F _{in} = 133.25 MHz ⁽²⁾				
CM ₆	1% cross modulation distortion VHF high	F _{in} = 361.25 MHz		86		dBμV
CM ₇		F _{in} = 367.25 MHz ⁽²⁾		87		
CM9	1% cross modulation distortion UHF	F _{in} = 801.25 MHz		86		dBμV
VO(IF1)		F _{in} = 55.25 MHz ₍₃₎				
VO(IF3)	Foutput voltage VHF low	F _{in} = 127.25 MHz		117		dBμV
V _{O(IF4)}		F _{in} = 133.25 MHz ₍₃₎		447		
VO(IF6)	Foutput voltage VHF high	F _{in} = 361.25 MHz		117		dBμV
VO(IF7)		F _{in} = 367.25 MHz ₍₃₎				
VO(IF9)	Foutput voltage UHF	F _{in} = 801.25 MHz		117		dBμV

(1) IF = 43 MHz, RF input level = 80 dB μ V (2) F_{undes} = F_{des} ± 6 MHz, pin = 80 dB μ V, AM 1 kHz, 30%, DES/CM = S/I = 46 dB (3) IF = 45.75 MHztop

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BLOCK DIAGRAM





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Terminal Functions

TERMINAL			
NAME	NO.	DESCRIPTION	
VLO OSC B VLO OSC C			
OSC GND	3	Oscillator ground	
VHI OSC B VHI OSC C	4	VHF hi oscillator input base VHF hi oscillator output collector	
UHF OSC B1	6	UHF oscillator input base1	
UHF OSC C1	7	UHF oscillator output collector1	
UHF OSC C2	8	UHF oscillator output collector2	
UHF OSC B2	9	UHF oscillator input base2	
IF GND	10	IF ground	\overline{m} \overline{m}
IF OUT1	11	IF output IF output	
VCC	13	Supply voltage for mixer/oscillator/PLL: 5 V	



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TERMINAL			
NAME	NO.	DESCRIPTION	
CP	14	Charge pump output	
VTU	15	Tuning voltage amplifier output	
TUVCC	16	Supply voltage for DC/DC converter: 5 V	
TUGND	17	DC/DC converter ground	
VDC	18	DC/DC converter monitor output. (Do not connect to other terminals or circuits except for the capacitor.)	
XTAL	19	4-MHz crystal oscillator input	
P8	20	Port 8 output (NPN open collector)	(20)
P7	21	Port 7 output (NPN open collector)	
P6	25	Port 6 output (NPN open collector)	
P5	27	Port 5 output (NPN open collector)	
SCL	22	I ² C serial clock input	
SDA	23	I ² C serial data input/output	
AS	24	I ² C address set input	
ADC/TEST	26	ADC input / test output	



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TERMINAL			
NAME	NO.	DESCRIPTION	
BS4	28	Band switch4 output (NPN emitter follower)	J
BS3	29	Band switch3 output (NPN emitter follower)	
BS2	30	Band switch2 output (NPN emitter follower)	50k \$ 30
BS1	31	Band switch1 output (NPN emitter follower)	
MIX OUT1	32	Mixer output	
MIX OUT2	33	Mixeroutput	
RF GND	34	RF ground	╎╺╲┯┘╸╵╶╲┯┘╸╵╶╴ │
VHF RF IN1 VHF RF IN2	35 36	VHF RF input	
			Ţ, Ţ, Ţ,
UHF RF IN1 UHF RF IN2	37 38	UHF RF input UHF RF input	



FUNCTION DESCRIPTION

The device can be controlled according to the $\mathsf{I}^2\mathsf{C}$ bus format.

Table 1. Serial Interface Function

PIN	PIN NAME	DESCRIPTION
22	SCL	Clock input
23	SDA	Datainput/output
24	AS	Address selection input
26	ADC/TEST	ADC input, test output

I^2C Write Mode (R/W = 0)

Table 2. Write Data Format

	MSB							LSB	
Address byte (ADB)	1	1	0	0	0	MA1	MA0	R/W=0	А
Divider byte 1 (DB1)	0	N14	N13	N12	N11	N10	N9	N8	А
Divider byte 2 (DB2)	N7	N6	N5	N4	N3	N2	N1	N0	А
Control byte (CB)	1	CP	T2	T1	T0	RSA	RSB	OS	А
Ports byte (PB)	P8	P7	P6	P5	BS4	BS3	BS2	BS1	А

Table 3. Description of Data Symbol

SYMBOL	DESCRIPTION	DEFAULT
MA1, MA0	Address set bits (See Table 4)	
N14N0	Programmable counter set bits N=N14x2^14+N13x2^13++N1x2+N0	Nn=0
СР	Charge pump current set bit 10 µA (CP=0) 40 µA (CP=1)	CP=1
T2, T1, T0	Test bits (See Table 5) Normal mode: T2=0, T1=0, T0=1/0	T2=0, T1=0, T0=0
RSA, RSB	Reference divider ratio selection bits (See Table 6)	RSA=0, RSB=1
OS	Tuning amplifier control bit Tuning voltage ON (OS=0) Tuning voltage OFF, high impedance (OS=1)	OS=0
BS4BS1	Band switch ports control bits BSn=0:Tr=OFF BSn=1:Tr=ON Band selection by BS1, 2, 4 (x: don't care) BS1 BS2 BS4 VHF–Lo 1 0 0 VHF–Hi x 1 0 UHF x x 1	BSn=0
P8P5	NPN open collector ports control bits Pn=0: Tr=OFF Pn=1: Tr=ON	Pn=0
Х	Don't care	

NOTE: A: Acknowledge

Table 4. Address Selection

VOLTAGE APPLIED ON AS INPUT	MA1	MA0
0 V to 0.1 V _{CC}	0	0
Always valid	0	1
0.4 V _{CC} to 0.6 V _{CC}	1	0
0.9 V _{CC} to V _{CC}	1	1

T2	T1	Т0	FUNCTION	
0	0	0	Normaloperation	Default
0	0	1	Normaloperation	
0	1	Х	Charge pump off	
1	1	0	Charge pump sink	
1	1	1	Charge pump source	
1	0	Х	Test mode	Not available ADC

Table 5. Test Blts

Table 6. Ratio Select Bits

RSA	RSB	REFERENCE DIVIDER RATIO
Х	0	640
0	1	1024
1	1	512

I²C Read Mode (R/W = 1)

Table 7. Read Data Format

	MSB							LSB	
Address byte (ADB)	1	1	0	0	0	MA1	MA0	R/W=1	А
Status byte (SB)	POR	FL	1	1	1	A2	A1	A0	Α

NOTE: A: Acknowledge

Table 8. Description of Data Symbol

SYMBOL	DESCRIPTION	DEFAULT
MA1, MA0	Address set bits (see Table 4)	
POR	Power-on reset flag POR Set: Power on POR Reset: End-of-data transmission procedure	POR=1
FL	In-lock flag PLL lock (FL=1) Unlock (FL=0)	
A2A0	Digital data of ADC (see Table 9)	

Table 9. ADC Level

VOLTAGE APPLIED ON ADC INPUT	A2	A1	A0
0.6 V _{CC} to V _{CC}	1	0	0
0.45 V _{CC} to 0.6 V _{CC}	0	1	1
0.3 V _{CC} to 0.45 V _{CC}	0	1	0
0.15 V _{CC} to 0.3 V _{CC}	0	0	1
0 V _{CC} to 0.15 V _{CC}	0	0	0

(1) Accuracy is 0.03 x V_{CC}.



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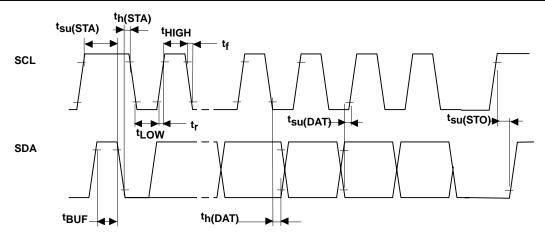
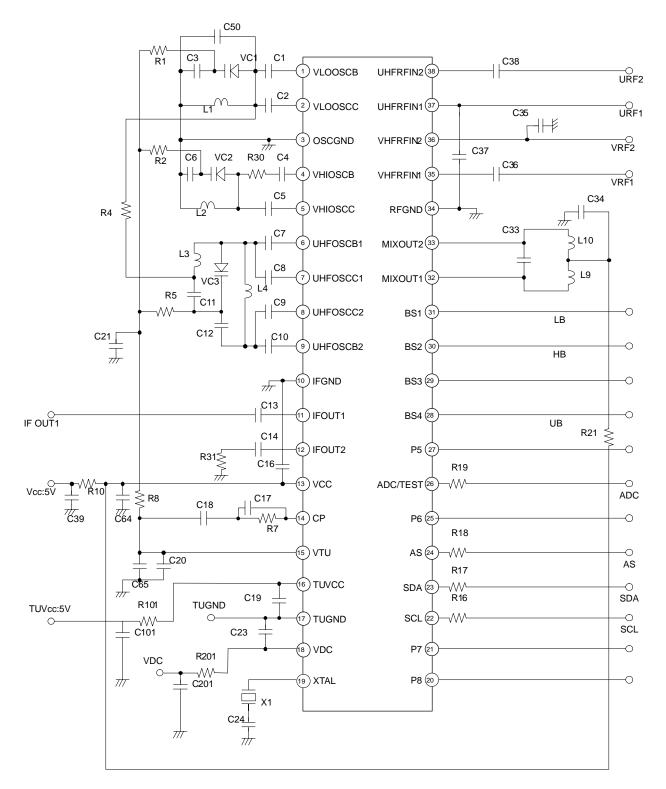


Figure 1. I²C Timing Chart



APPLICATION INFORMATION



(1) It is recommended that designers be careful with the PCB layout and coupling to minimize the effects of the higher harmonics of Xtal oscillation from the dc/dc converter section (pin 16–20) to mixer and oscillator section.



COMPONENT VALUES FOR MEASUREMENT CIRCUIT (TENTATIVE)

PART NAME	VALUE			
C1, C2, C4	1 pF			
C3	47 pF			
C5	1.5 pF			
C6	56 pF			
C7–C10	1 pF (axial ceramic)			
C11	100 pF			
C12	13 pF (axial ceramic)			
C13, C14, C16, C17, C19–C21, C34–C39, C64, C101	2.2 nF			
C18, C23	0.047 μF			
C24	68 pF			
C33	18 pF			
C41, C60, C62, C201	Not mounted			
C50	3 pF			
R1 , R2, R4, R5, R8	33 kΩ			
R7	100 kΩ			
R10, R21, R101, R201	0 Ω			
R16–R19	330 Ω			
R30	20 Ω			
R31	50 Ω			
L1	2.6¢, 8T, wire 0,3 mm			
L2	2.4¢, 4T, wire 0,4 mm			
L3	2.8ø, 2T, wire 0,4 mm			
L4	2.1ø, 3T, wire 0,4 mm			
L9, L10	2.5ø, 16T, wire 0,25 mm			
VC1, VC2, VC3	1T363A			
X1	4 MHz			



TEST CIRCUIT

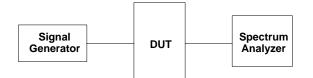


Figure 3. Measurement Circuit of Conversion Gain

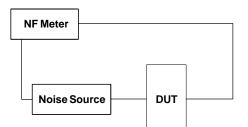


Figure 4. Noise Figure Measurement Circuit

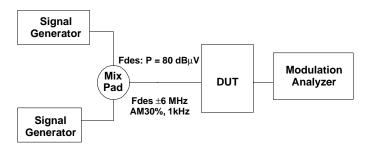


Figure 5. 1% Cross Modulation Distortion Measurement Circuit



S-PARAMETER

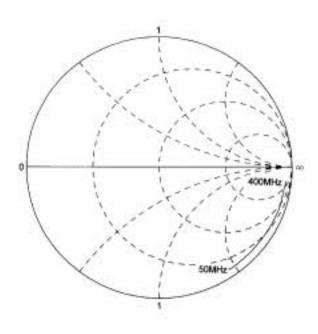


Figure 6. VHF Input

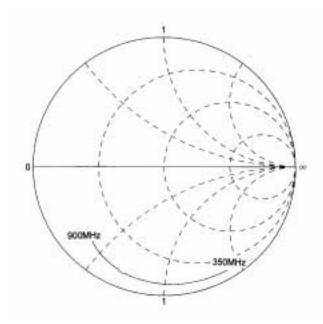


Figure 7. UHF Input



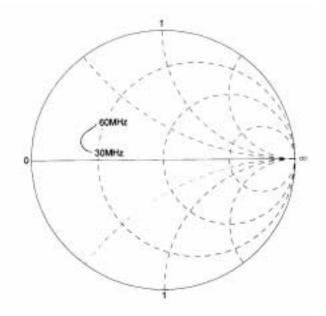


Figure 8. IF Output

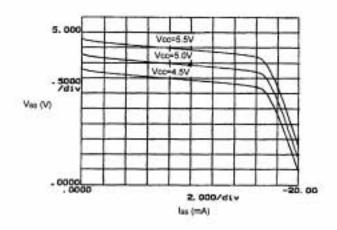


Figure 9. Band Switch Driver Output Voltage (BS1-BS4)



24-Apr-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN761677DA	OBSOLETE	TSSOP	DA	38		TBD	Call TI	Call TI	-20 to 85	SN761677	
SN761677DAR	OBSOLETE	TSSOP	DA	38		TBD	Call TI	Call TI	-20 to 85	SN761677	
SN761677DBTR	OBSOLETE	TSSOP	DBT	38		TBD	Call TI	Call TI		B1677	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and package die adhesive used between the die and package die adhesive used between the die adhesive used between the die adhesive use

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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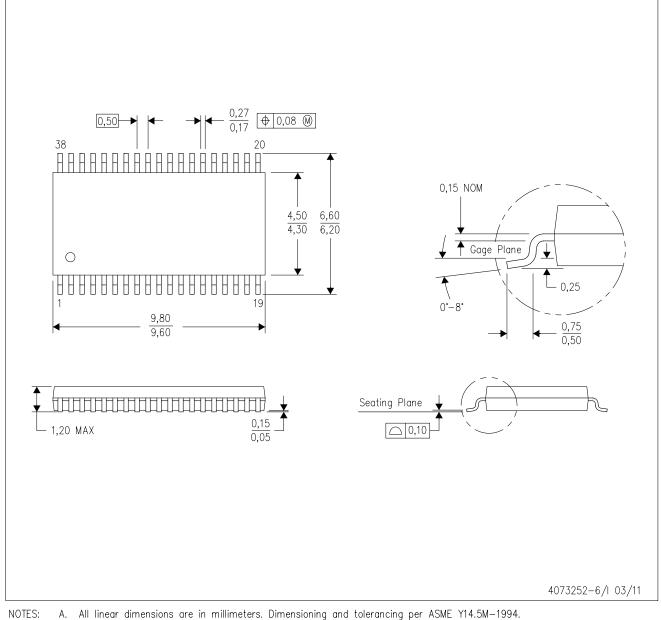
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DBT (R-PDSO-G38)

PLASTIC SMALL OUTLINE



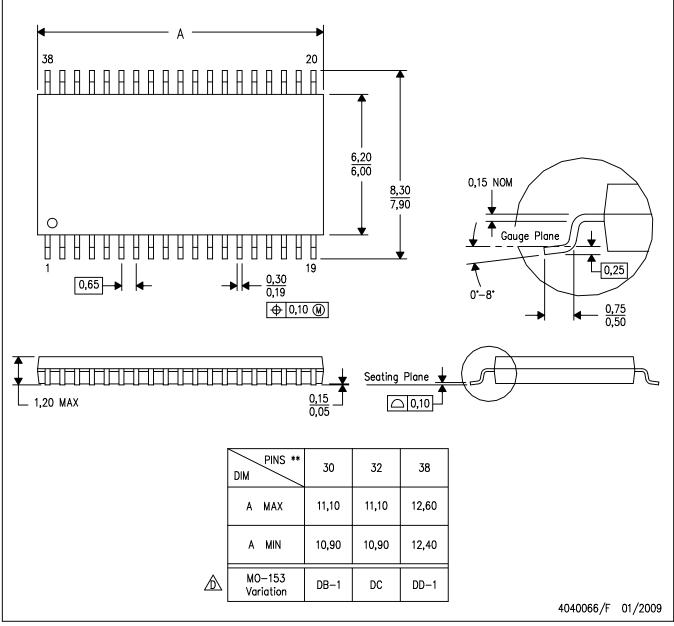
B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-153.



DA (R-PDSO-G**) 38 PIN SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

🛆 Falls within JEDEC MO-153, except 30 pin body length.



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